

AH9280

General Description

The AH9280 is a most advanced smart fan controller and Hall IC driver manufactured by special CMOS process. It is designed for 5V and 12V cooling fan. To allow survival in a harsh environment and lower the total system cost, the AH9280 has been designed with many powerful functions while almost eliminating all discrete components, such as, capacitor, resistor, transistor, diode and PC board.

The AH9280 can operate normally in an ambient temperature up to 125°C due to its Hall IC circuitry and power MOSFET output that allow low power dissipation.

When there is no motion for one second, the IC will automatically detect the locked rotor conditions, and enter protection mode, shutting off the motor driver for five seconds. Then, the IC will turn on the motor driver for one second to detect whether there is rotation condition, if fails, the IC will shut off motor driver for five seconds again. This sequence will be repeated until rotation condition is detected, and the IC enters normal operation. This feature can effectively prevent the AH9280 from overheating and damage due to long-time locked rotor condition.

Specially designed for driving large fans, the AH9280 is optimized for low start-up voltage.

The AH9280 is available in TO-94 package.

Features

- High-sensitivity Integrated Hall Sensor
- Low Start-up Voltage
- 5V and 12V Operation
- Peak Output Current up to 1200mA
- Power-efficient CMOS and Power MOSFETs
- Built-in Output Protection Clamping Diode
- Locked Rotor Shutdown and Auto-restart
- ESD Rating: 6000V (Human Body Model) 400V (Machine Model)

Applications

- 5V/12V DC Brushless Motor/Fan
- PC, Server, Laptop Cooling Fan
- Power Supply Cooling Fan
- Large/Small Sized Fan

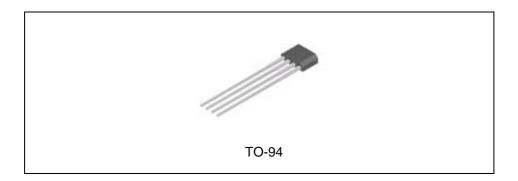


Figure 1. Package Type of AH9280



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Pin Configuration

Z4 Package (TO-94)

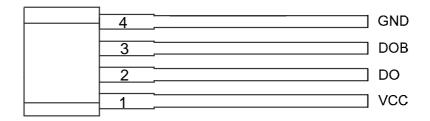


Figure 2. Pin Configuration of AH9280 (Front View)

Pin Description

Pin Number	Pin Name	Function			
1	VCC	Power supply pin			
2	DO	Output pin 1			
3	DOB	Output pin 2			
4	GND	Ground pin			



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Functional Block Diagram

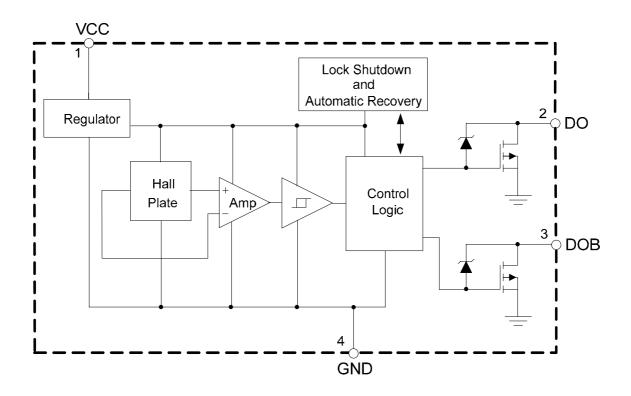
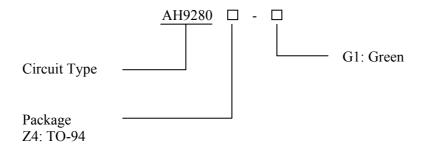


Figure 3. Functional Block Diagram of AH9280

Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing Type	
TO-94	-40 to 125°C	AH9280Z4-G1	9280Z4-G1	Bulk	

BCD Semiconductor's Pb-free products, as designated with "G1" suffix in the part number, are RoHS compliant and green.



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Absolute Maximum Ratings (Note 1, T_A=25°C)

Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	18	V
Peak Output Current	I_{OUT_P}	1200	mA
Continuous Output Current	I_{OUT_C}	600	mA
Supply Current (Fault)	I_{CC}	6	mA
Power Dissipation	P_{D}	600	mW
Thermal Resistance (Junction to Ambient)	$ heta_{ m JA}$	208	°C/W
Storage Temperature	T_{STG}	-55 to 150	°C
ESD (Human Body Model)	ESD	6000	V
ESD (Machine Model)	ESD	400	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V_{CC}	2.5	16	V
Ambient Temperature	T_A	-40	125	°C



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Electrical Characteristics

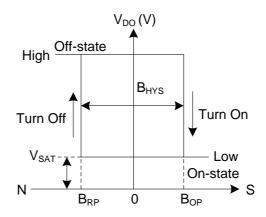
 V_{CC} =12V, T_A =25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Supply Voltage	V_{CC}	Operating	2.5	12	16	V
Supply Current	I_{CC}	Average		4	6	mA
Output Current	I _{OUT}				500	mA
Output Leakage Current	I _{LEAKAGE}			0.1	10	μΑ
Saturation Voltage	V_{SAT}	I _{OUT} =350mA		600	1000	mV
Output On Time	T _{ON}			0.8		S
Output Off Time	T_{OFF}			5		S
Output Zener Break-down Voltage	Vz			35		V

Magnetic Characteristics

 V_{CC} =12V, T_A =25°C, unless otherwise specified.

Parameter	Symbol	Min	Тур	Max	Unit
Operating Point	${ m B}_{ m OP}$		20	50	Gauss
Releasing Point	B_{RP}	-50	-20		Gauss
Hysteresis	$\mathrm{B}_{\mathrm{HYS}}$		40		Gauss



Magnetic Flux Density (Gauss)



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Test Circuit

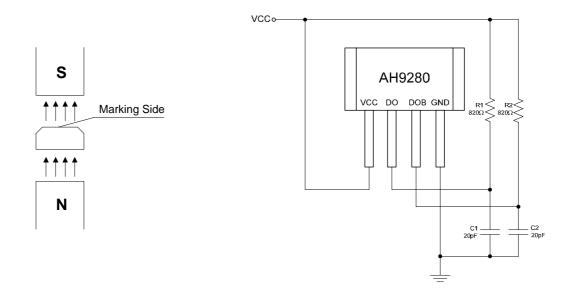


Figure 4. Basic Test Circuit of AH9280

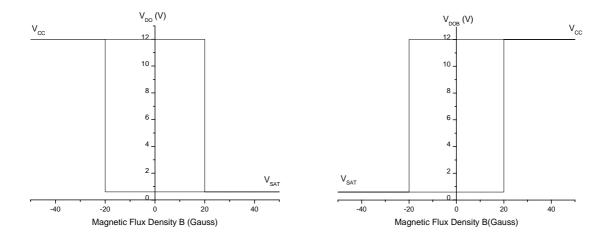


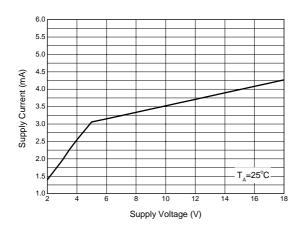
Figure 5. V_{DO} vs. Magnetic Flux Density

Figure 6. V_{DOB} vs. Magnetic Flux Density



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Typical Performance Characteristics



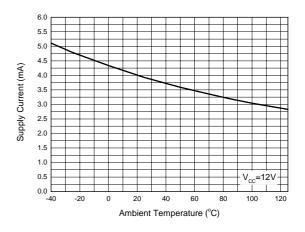
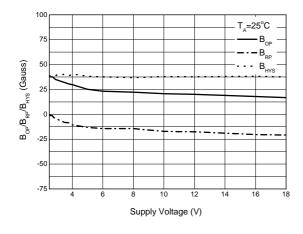


Figure 7. Supply Current vs. Supply Voltage

Figure 8. Supply Current vs. Ambient Temperature



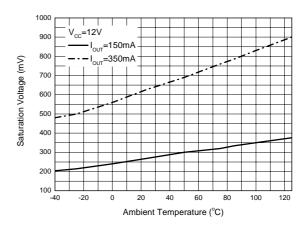


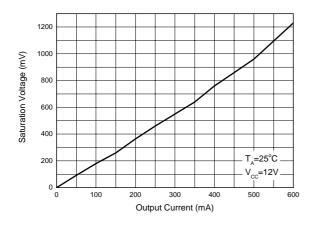
Figure 9. B_{OP}/B_{RP}/B_{HYS} vs. Supply Voltage

Figure 10. Saturation Voltage vs. Ambient Temperature



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Typical Performance Characteristics (Continued)



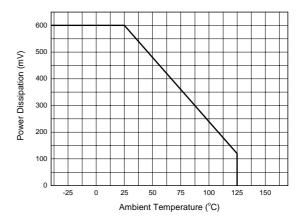


Figure 11. Saturation Voltage vs. Output Current

Figure 12. Power Dissipation vs. Ambient Temperature

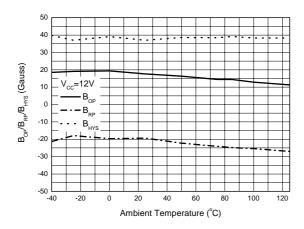


Figure 13. Bop/BRP/BHYS vs. Ambient Temperature



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Typical Application

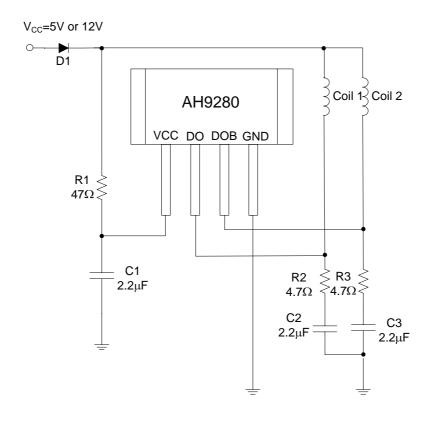


Figure 14 Typical Application 1 of AH9280 (Note 2)

Note 2:

- 1. D1 is an ordinary diode used to filter the noise from VCC and protect IC if VCC and GND are plugged reversed.
- 2. R1=47 Ω typical.
- 3. $C1=C2=C3=2.2\mu F$ typical, electrolytic capacitors are better. They should be fine tuned based on system design.
- 4. R2=R3= 4.7Ω typical. They can be removed according to system requirement.



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Typical Application (Continued)

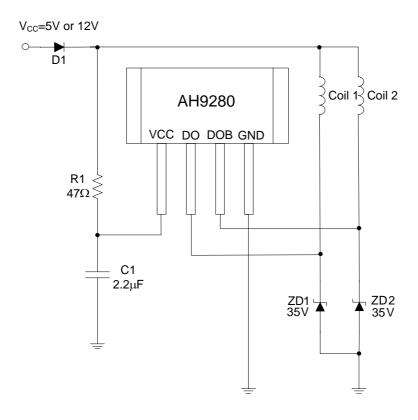


Figure 15. Typical Application 2 of AH9280 (Note 3)

Note 3:

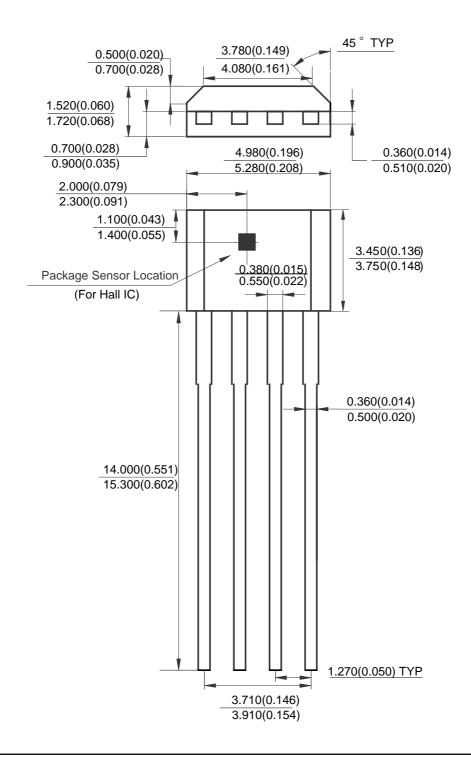
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- 2. R1=47 Ω typical.
- 3. C1 = $2.2\mu F$ typical, electrolytic capacitors are better. They should be fine tuned based on system design.
- 4. ZD1 and ZD2 breakdown voltage are 35V.



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Mechanical Dimensions

TO-94 Unit: mm(inch)







BCD Semiconductor Manufacturing Limited

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